Silicon PNP Epitaxial

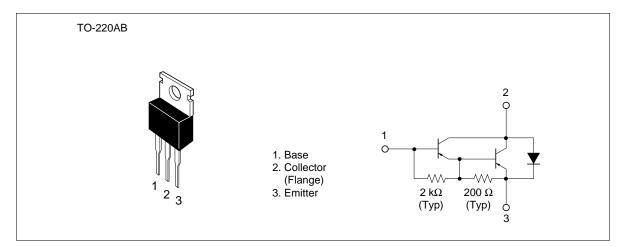
HITACHI

ADE-208-858 (Z) 1st. Edition Sep. 2000

Application

Medium speed and power switching complementary pair with 2SD970(K)

Outline



Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

Symbol	Rating	Unit	
V _{CBO}	-120	V	
V _{CEO}	V _{CEO} –120		
V_{EBO}	-7	V	
Ι _c	-8	А	
I _{C(peak)}	-12	А	
P _c * ¹	40	W	
Tj	150	°C	
Tstg	-55 to +150	°C	
	V_{CBO} V_{CEO} V_{EBO} I_{C} $I_{C(peak)}$ P_{c}^{*1} Tj	V_{CBO} -120 V_{CEO} -120 V_{CEO} -7 I_c -8 $I_{C(peak)}$ -12 P_c^{*1} 40 Tj 150	

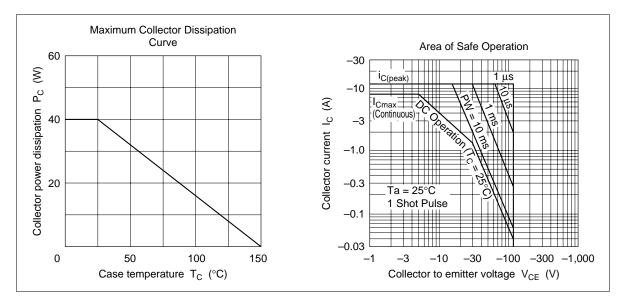
Note: 1. Value at $T_c = 25^{\circ}C$

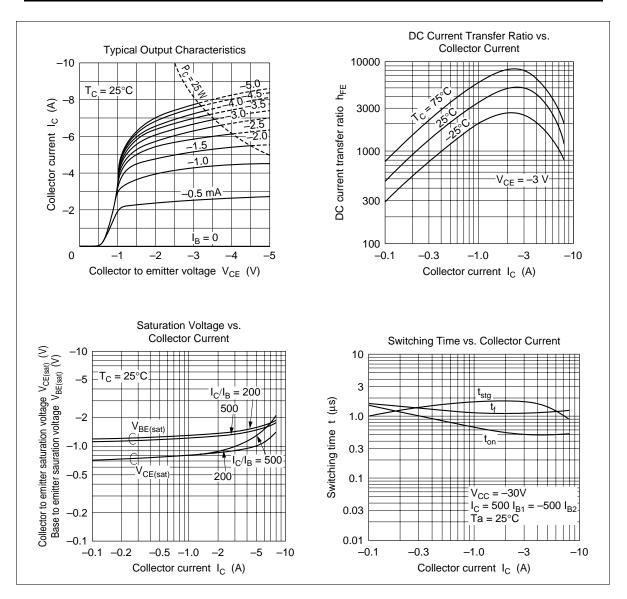


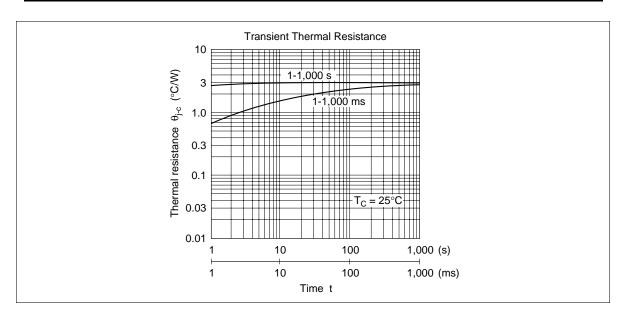
Electrical Characteristics (Ta = 25°C)

Symbol	Min	Тур	Max	Unit	Test conditions
N V _{(BR)CEO}	-120	_		V	$I_c = -25 \text{ mA}, \text{ R}_{BE} = \infty$
$V_{(BR)EBO}$	-7	_	_	V	$I_{\rm E} = -50$ mA, $I_{\rm C} = 0$
I _{CBO}	_	—	-100	μA	$V_{CB} = -120 \text{ V}, I_{E} = 0$
I _{CEO}	_	—	-10	μA	$V_{ce} = -100 \text{ V}, \text{ R}_{be} = \infty$
h _{FE}	1000	_	20000		$V_{ce} = -3 V, I_c = -4 A^{*1}$
$V_{\text{CE(sat)(1)}}$	—	_	-1.5	V	$I_{\rm C} = -4$ A, $I_{\rm B} = -8$ mA ^{*1}
V _{CE(sat)(2)}	—	—	-3.0	V	$I_{\rm c} = -8$ A, $I_{\rm B} = -80$ mA ^{*1}
$V_{\text{BE(sat)(1)}}$	—	_	-2.0	V	$I_{\rm C} = -4$ A, $I_{\rm B} = -8$ mA ^{*1}
V _{BE(sat)(2)}	—	_	-3.5	V	$I_{\rm c} = -8$ A, $I_{\rm B} = -80$ mA ^{*1}
t _{on}	—	0.5		μs	$I_{c} = -4 \text{ A}, I_{B1} = I_{B2} = -8 \text{ mA}$
t _{stg}	—	1.6		μs	
t _f	_	1.5		μs	
	$\begin{tabular}{ c c c c } \hline V_{(BR)CEO} & \hline V_{(BR)EBO} & \hline \\ \hline & & & & & & & & \hline & & & & & & & \hline & & & & & \hline & & & & & \hline & & & & & \hline & & & & & \hline & & $	$\begin{array}{c c} & & & & -120 \\ \hline & & & & & \\ V_{(BR)EBO} & & -7 \\ \hline & & & & \\ I_{CBO} & & \\ \hline & & & & \\ I_{CEO} & & \\ \hline & & & & \\ I_{CEO} & & \\ \hline & & & & \\ V_{CE(sat)(1)} & & \\ \hline & & & & \\ V_{CE(sat)(2)} & & \\ \hline & & & & \\ V_{BE(sat)(2)} & & \\ \hline & & & & \\ t_{on} & & \\ \hline & & & \\ t_{stg} & & \end{array}$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

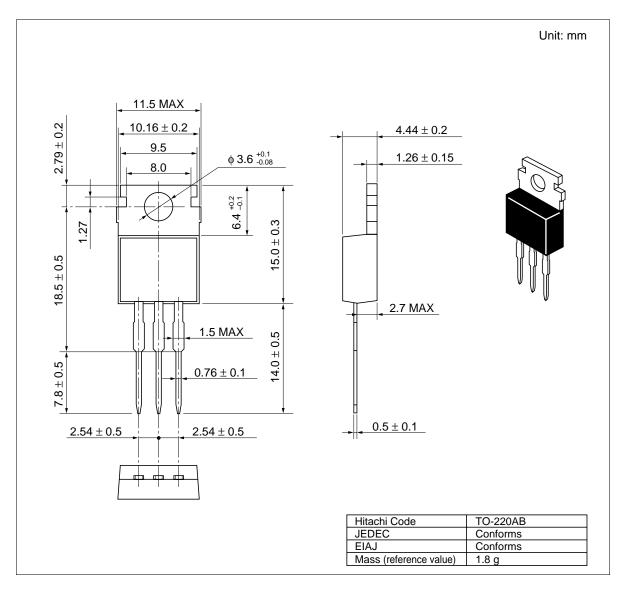
Note: 1. Pulse test







Package Dimensions



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